

Task #1: The tools

a) A transient simulation is a simulation in the time-domain.
b) The transistor parameters use the SPICE naming conventions and are as follows[1]:

- $vt0$: zero-bias threshold voltage [V]
- kp : transconductance $\left[\frac{A}{V^2}\right]$
- γ : Bulk threshold parameter $[V^{\frac{1}{2}}]$
- λ : Channel-length modulation $[V^{-1}]$
- ϕ : Surface inversion potential [V]

c) Node 0 is GND (or 0V).

d)

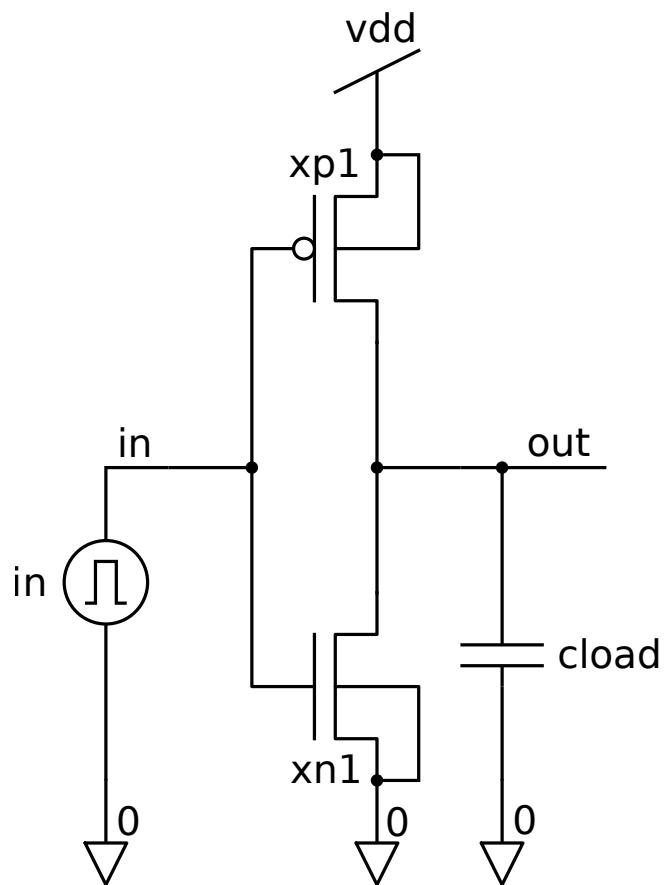


Figure 1: Inverter schematic specified by Spectre netlist file. Instantiated components and nets labeled.

Task #2: The lab

Task #3: The Spectre netlist file

Task #4: The capacitances of the H-tree

Ignoring (shorting) the resistances of the H-tree directly connects all the capacitances to the output node of the tapered buffer. The total capacitance is then simply the sum of the individual wire and leaf-inverter input capacitances.

Since none of the wire widths exceed $2\text{ }\mu\text{m}$, the wire capacitance can be assumed to be $0.2\text{ fF}/\mu\text{m}$.

$$\begin{aligned}C_{W1} &= 10\text{ mm} \cdot 0.2\text{ fF}/\mu\text{m} = 2\text{ pF} \\C_{W2} &= 7.07\text{ mm} \cdot 0.2\text{ fF}/\mu\text{m} = 1.414\text{ pF} \\C_{W2} &= 5\text{ mm} \cdot 0.2\text{ fF}/\mu\text{m} = 1\text{ pF}\end{aligned}$$

The input capacitance of an X1 inverter was found in *lab 1* to be 0.36 fF , therefore the input capacitance of the scaled up inverter on the leaves is $1000 \cdot 0.36\text{ fF} = 0.36\text{ pF}$.

The total capacitance of the (zero-resistance) H-tree is

$$C_{\text{H-tree}} = 2C_{W1} + 4C_{W2} + 8C_{W3} + 8000 \cdot C_{\text{in},\text{X1}} = 20.536\text{ pF}$$

Task #5: Design of the tapered buffer

If we let $C = C_{\text{in},\text{X1}} = 0.36\text{ pF}$ (ie. the input capacitance of an X1 inverter), and use it as a reference value, then the capacitive load of the H-tree can be *normalized* as $\frac{20.536\text{ pF}}{0.36\text{ pF}} = 57044C$.

Next, the various *path efforts* can be determined

- $G = 1$
- $B = 1$
- $H = \frac{57044C}{4C} = 14261$

This gives a *path effort* of $F = GBH = 14261$.

It can be shown that the *path delay* is at a minimum when all the *stage efforts* are equal and approximately 4. Thus the optimum number of stages is chosen to achieve this result as closely as possible.

$$\hat{N} = \log_4(F) = 6.9$$

At this point a value of either 6 or 7 could be chosen. Both will be evaluated here to determine which is more appropriate.

For $\hat{N} = 7$ the minimum *path delay* $D = \hat{N} \cdot \sqrt[7]{F} + P = 7 \cdot \sqrt[7]{14261} + 7 = 34.5$ and the *stage effort* $\hat{f} = \sqrt[7]{14261} = 3.92$.

For $\hat{N} = 6$, however, the minimum *path delay* $D = 35.5$ and the *stage effort* $\hat{f} = 4.92$. The fact that the delay is insensitive to the number of stages means that accepting a marginal increase in delay (1ps, or 2.8%) allows an area reduction of 14% along with the associated power consumption!

Since this is arguably the superior implementation, it will be used going forward. Finally the absolute *path delay* is $t_{\text{pd}} = 35.5\tau = 177\text{ ps}$, where $\tau = 5\text{ ps}$. As a consequence of all the individual *path efforts* being equal, the delays between each stage are also equal ie. $d_i = g_i h_i + p_i = 5.92$ or 29.6 ps in absolute terms.

Task #6: The Resistances (and capacitances) of the H-tree

The resistance of a wire segment can be calculated from its *sheet resistance* and its physical dimensions

$$R_W = R_{sh} \frac{L}{W}$$

, note height (or thickness) is disregarded in this model.

The dimensions of the wires are known and R_{sh} is assumed to be 0.01Ω . Thus, the resistance of the wires at each level can be calculated as

- $R_{W1} = 50 \Omega$
- $R_{W2} = 50.1 \Omega$
- $R_{W3} = 50 \Omega$

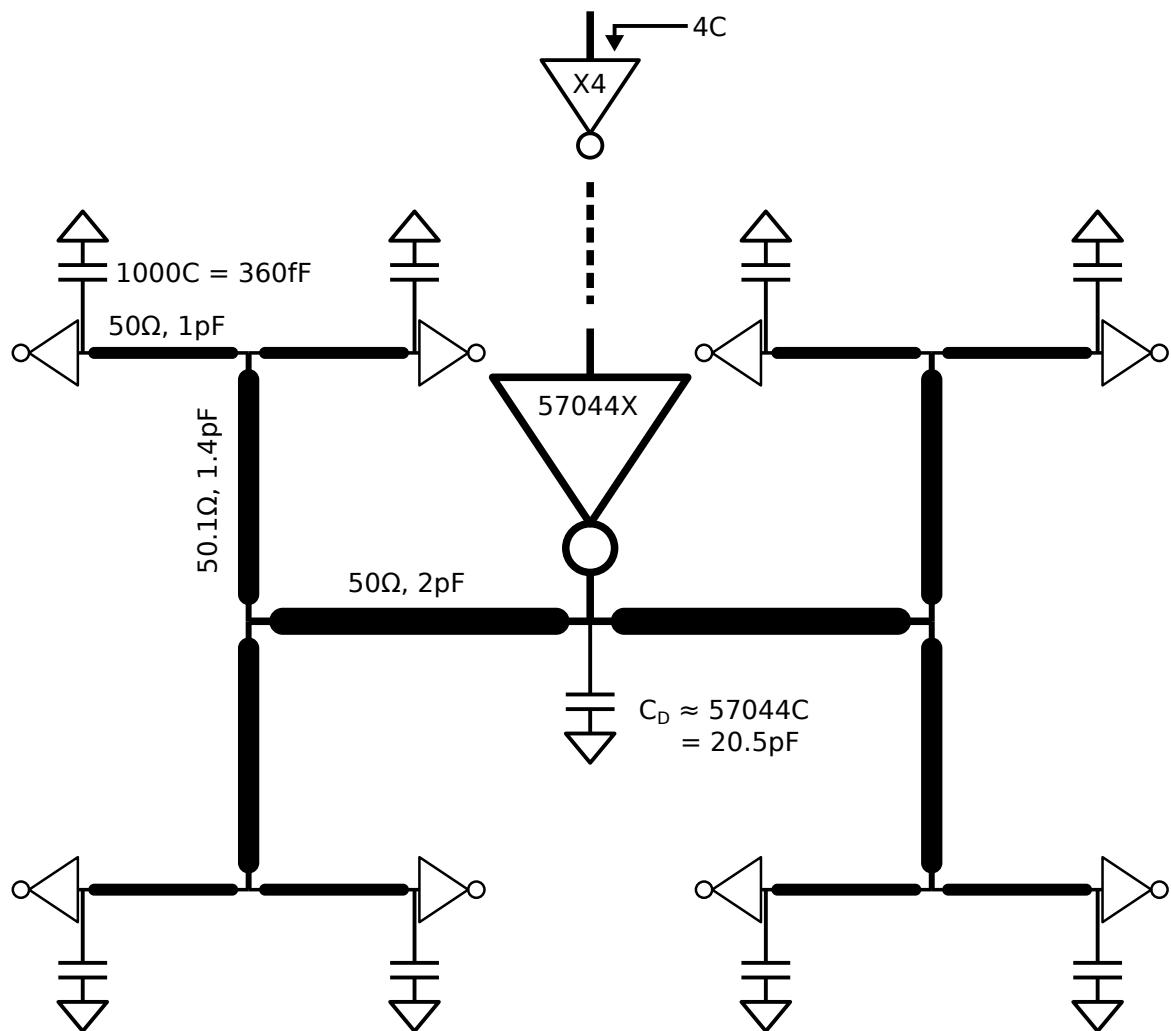


Figure 2: H-tree with calculated resistances and capacitances.

Task #7: Delay of the H-tree with capacitance and resistance when driven by the tapered buffer

The H-tree is fully symmetrical and when modeled as lumped components, parallelism becomes evident, allowing the tree to be "collapsed" into a single path with no branches. This results in the following schematic

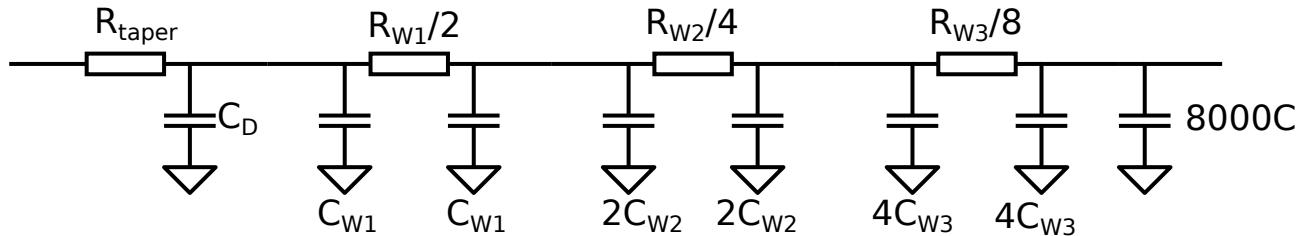


Figure 3: The "collapsed" H-tree, as a non-branching RC-chain.

The Elmore delay of this reduced H-tree is calculated in the following formula

$$\begin{aligned}
 T_E = & R_{\text{rep}}(C_D + 8000C + 2C_{w1} + 4C_{w2} + 8C_{w3}) + \\
 & R_{w1}/2(C_{w1} + 4C_{w2} + 8C_{w3} + 8000C) + \\
 & R_{w2}/4(2C_{w2} + 8C_{w3} + 8000C) + \\
 & R_{w3}/8(4C_{w3} + 8000C) \\
 = & 692.6 \text{ ps}
 \end{aligned}$$

After compensating for the behaviour of ramped signal inputs (scaling the delay by 0.7) the Elmore delay is 484.8ps.

Task #8: Delay with inverters in the H tree driven by tapered buffer

The buffers inserted into the H-tree can be modeled as an effective resistance with an input and output capacitance. The output (diffusion) capacitance C_D is assumed to be equal to the input capacitance C_{in} . The effective resistance of an X1 inverter was determined in *lab 1* to be $20\text{ k}\Omega$. Since the tree is still symmetrical it can again be collapsed into a single path. Since the inverters do not provide a direct electrical path between the input and the output, the path must be divided into segments with the Elmore delay calculated for each segment individually.

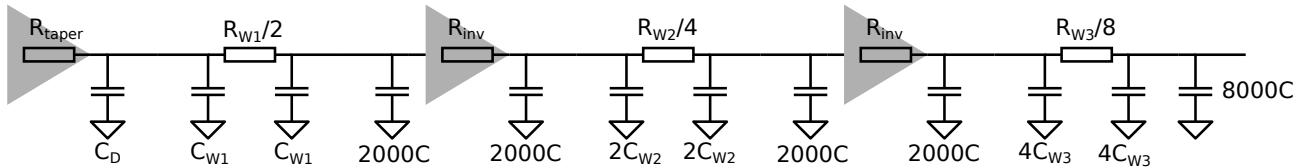


Figure 4: Collapsed H-tree with inserted buffers.

The uncompensated Elmore delay for each segment is thus (segments numbered left to right in fig 4)

$$T_{E_1} = R_{taper}(C_D + C_{w1} + C_{w1} + 2000C) + \frac{R_{w1}}{2}(C_{w1} + 2000C) = 76,8\text{ps}$$

$$T_{E_2} = R_{inv}(2000C + 2C_{w2} + 2C_{w2} + 2000C) + \frac{R_{w2}}{4}(2C_{w2} + 2000C) = 115,4\text{ps}$$

$$T_{E_3} = R_{inv}(2000C + 4C_{w3} + 4C_{w3} + 8000C) + \frac{R_{w3}}{8}(4C_{w3} + 8000C) = 159,0\text{ps}$$

, resulting in a total delay of 351.3ps . Once the results are compensated to take into account ramped input signals, the results are as follows

$$T_{E_1} = 53,8\text{ps}$$

$$T_{E_2} = 80,8\text{ps}$$

$$T_{E_3} = 111,3\text{ps}$$

, with a total of delay of $245,9\text{ps}$.

References

[1] *M. MOSFET*. URL: http://ltwiki.org/LTspiceHelp/LTspiceHelp/M_MOSFET.htm.